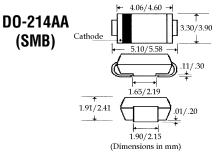
# 2.0 Amp SURFACE MOUNT PLASTIC SILICON DIODES

### **Description**

## **Mechanical Dimensions**





#### **Features**

SMB21...210 Series

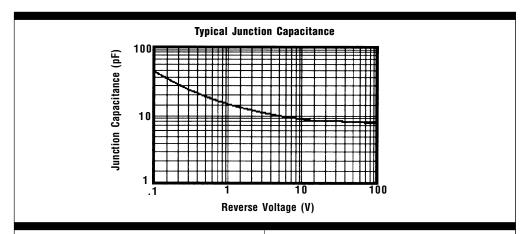
- **LOW COST**
- **HIGH CURRENT CAPABILITY**
- HIGH SURGE CAPABILITY

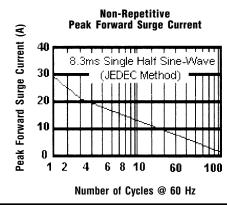
- LOW FORWARD VOLTAGE WITH LOW LEAKAGE CURRENT
- MEETS UL SPECIFICATION 94V-0

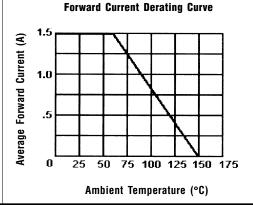
	SMB21 210 Series						Units
Maximum Ratings	SMB21	SMB22	SMB24	SMB26	SMB28	SMB210	
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	100	200	400	600	800	1000	Volts
RMS Reverse VoltageV <sub>R(rms)</sub>	70	140	280	420	560	700	Volts
DC Blocking Voltage $V_{\rm DC}$	100	200	400	600	800	1000	Volts
Average Forward Rectified CurrentI <sub>F(av)</sub>				2.0			Amps
Non-Repetitive Peak Forward Surge CurrentI <sub>FSM</sub>				50			Amps
Operating & Storage Temperature Range $T_J$ , $T_{STRG}$			65	to 175			°C
Electrical Characteristics							
Maximum Forward Voltage @ 2.0AV <sub>F</sub>				1.1			Volts
Maximum Full Load Reverse CurrentI <sub>R</sub> (av)				30			μAmps
Maximum DC Reverse CurrentI <sub>R</sub> @ Rated DC Blocking Voltage $T_c = 25^{\circ}C$ $T_c^{\circ} = 75^{\circ}C$				5.0 50			μAmps μAmps
Typical Junction CapacitanceC <sub>J</sub> (Note 1)				30			pF



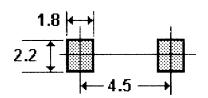
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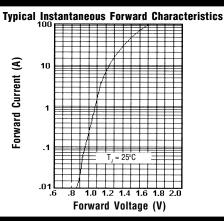






### **Recommended Soldering Pad Layout**





Ratings at 25 Deg. C ambient temperature unless otherwise specified.

Single Phase Half Wave, 60 Hz Resistive or Inductive Load.

For Capacitive Load, Derate Current by 20%.

NOTES: 1. Measured @ 1 MHz and applied reverse voltage of 4.0V.